



## **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	2.0Ω @ V <sub>GS</sub> = 5V	350mA
50V	2.5Ω @ V <sub>GS</sub> = 2.5V	320mA
	4.0Ω @ V <sub>GS</sub> = 1.8V	270mA

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Motor driving
- Power management functions
- Load switching

#### 50V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features and Benefits**

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

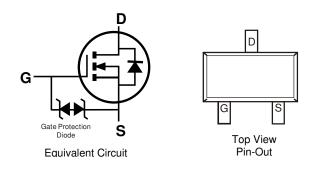
- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (©3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





SOT523

Top View



## Ordering Information (Note 4)

Dart Number	Daalyawa	Packing		
Part Number	Package	Qty.	Carrier	
DMN52D0LT-7	SOT523	3000	Tape & Reel	
DMN52D0LT-13	SOT523	10000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

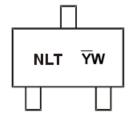
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



 $\frac{NLT}{YW}$  = Product Type Marking Code  $\frac{YW}{YW}$  = Date Code Marking

<u>Y</u> = Year (ex: 2 = 2022)

W = Week (ex: a = week 27; z represents week 52 and 53)

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3
Week 1-26					27-	-52		53				
Code	A-Z				a	-Z			2	2		

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain Source Voltage	V <sub>DSS</sub>	50	V		
Gate-Source Voltage	VGSS	±12	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = 5V Steady State		TA = +25°C TA = +70°C	ID	350 280	mA
Maximum Continuous Body Diode Forward Curre		ls	350	mA	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	IDM	1.2	A		
Pulsed Source Current (10µs Pulse, Duty Cycle =	lsм	1.2	A		

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	300	°C/W
Total Power Dissipation (Note 5)	i	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	246	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

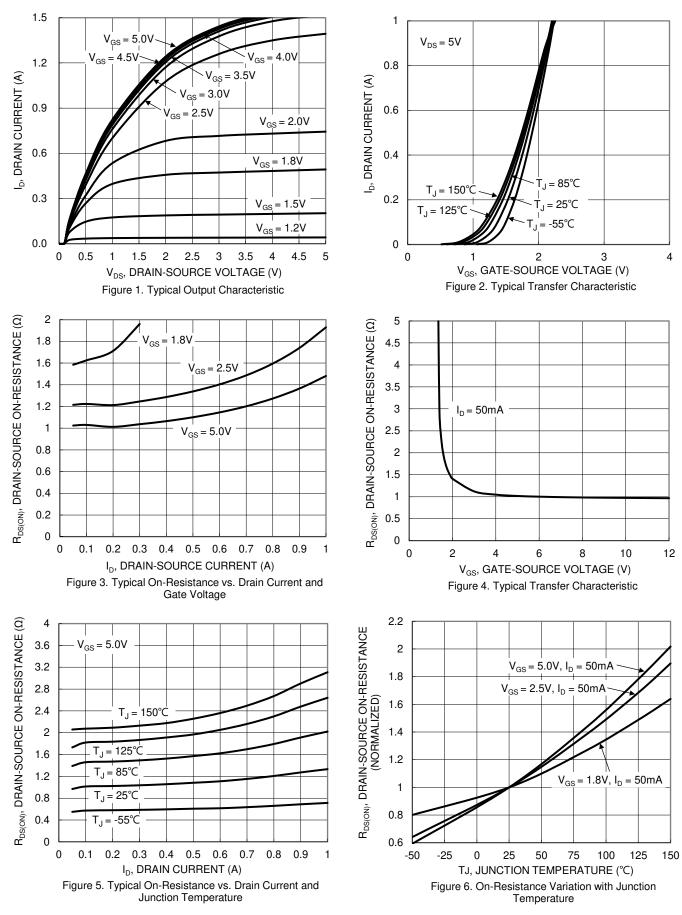


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

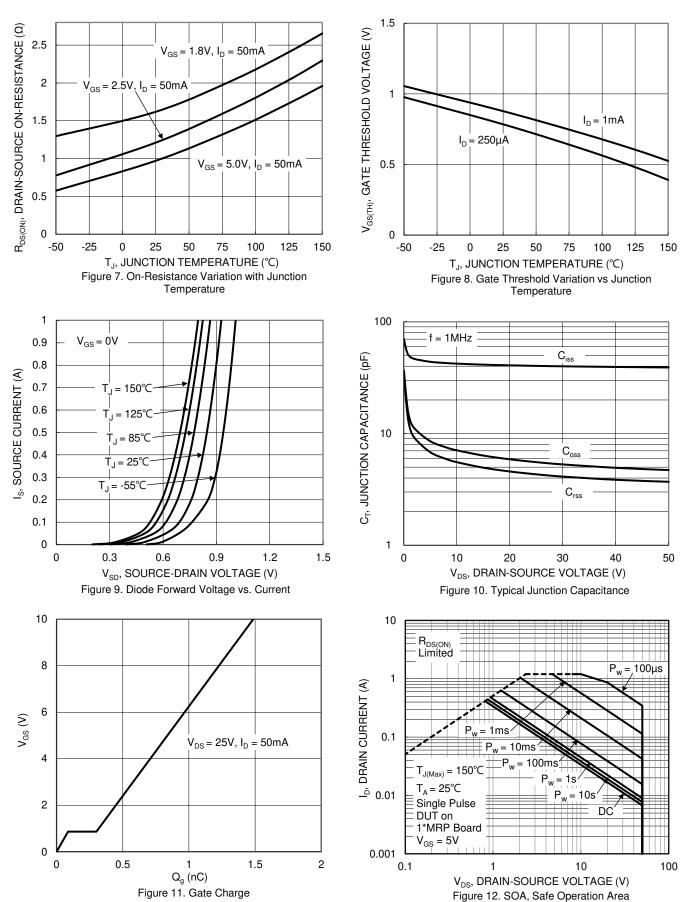
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Oymbol	WIIII	TYP	Max	onit	rest condition	
Drain-Source Breakdown Voltage	BVDSS	50	_	_	V	Vgs = 0V, ID = 10µA	
Zero Gate Voltage Drain Current		_	_	1	μA	$V_{DS} = 50V, V_{GS} = 0V$	
Gate-Body Leakage	Igss		_	10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.49	—	1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Ohat's Dusis Osuma On Dasistanas		—	0.97	2.0	0	$V_{GS} = 5.0V, I_D = 50mA$	
Static Drain-Source On-Resistance	Rds(on)	_	1.2 1.6	2.5 4.0	Ω	$V_{GS} = 2.5V, I_D = 50mA$ $V_{GS} = 1.8V, I_D = 50mA$	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	_	0.6	1.4	V	$V_{GS} = 0V, I_{S} = 50mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		40		pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	5.6	—	pF		
Reverse Transfer Capacitance	Crss	_	4.3	—	pF		
Gate Resistance	Rg	—	52	-	Ω	$V_{DS} = 0V, V_{GS} = 0V$ f = 1.0MHz	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		0.8	—	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	1.5	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	0.1	—	nC	$V_{DS} = 25V, I_D = 50mA$	
Gate-Drain Charge	Q <sub>gd</sub>	_	0.2	_	nC		
Turn-On Delay Time	td(on)	_	1.3	_	ns		
Turn-On Rise Time	tR	_	9.6	_	ns	$V_{DS} = 25V, V_{GS} = 10V$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	32	—	ns	$R_g=50\Omega,\ I_D=50mA$	
Turn-Off Fall Time	tF		41		ns		

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

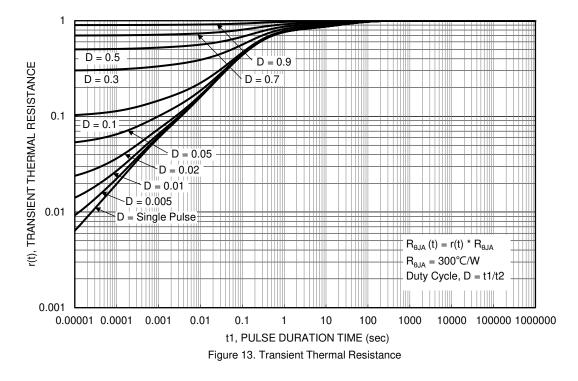








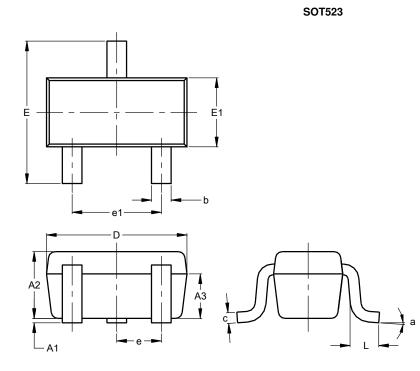






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

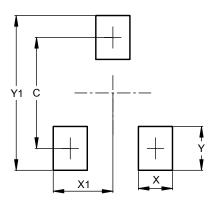


SOT523							
Dim	Min Max Typ						
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.10 0.20 0.12					
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75 0.85 0.80						
е		0.50 BS	С				
e1	0.90	0.90 1.10 1.00					
L	0.20	0.20 0.40 0.3					
а	0°		8°				
All Dimensions in mm							

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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